

THR40U03DB



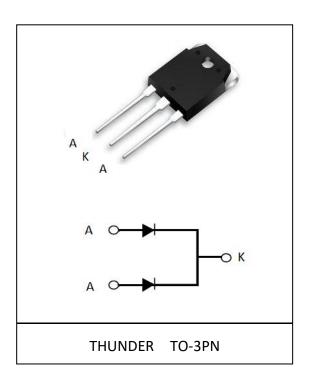
Thunder High Power Products

FRED Ultrafast Soft Recovery Diode, 40A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary		
VR	300 V	
lf(AV)	2*20A	
trr	23ns	



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		300	V
Continuous forward current	lf(AV)	Tc =110°C	40	
Single pulse forward current	İfsm	Tc =25°C	300	Α
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	100	
Operating junction	Tj		175	°C
Storage temperatures	Tstg		-55 to +175	°C

Rev.A01 1/4





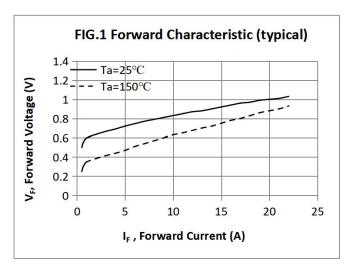
Electrical characteristics (Ta=25°C unless otherwise specified)

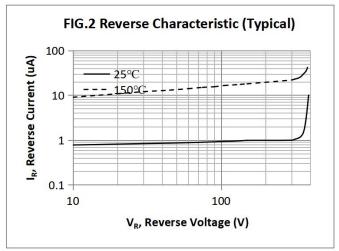
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units	
Breakdown voltage Blocking voltage	VBR, V _R	Ir=100µA	300				
Forward voltage (Per Diode)	VF	IF=20 A		0.98	1.20	V	
		IF=20A, Tj =125°C		0.90	1.00		
Reverse leakage IR current(Per Diode)		Vr= Vrrm			10		
	lR	Tj=150°C, Vr=300V			100	μ Α	
Reverse recovery time(Per Diode)		I _F =0.5A, I _R =1A, I _{RR} =0.25A		33	40		
	trr	I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		23	35	ns	

Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta$ JC	0.75	°C/W

Electrical performance (typical)



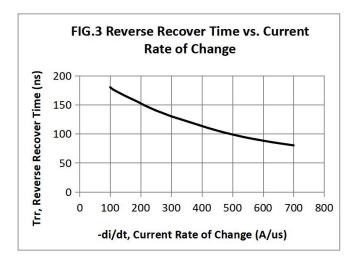


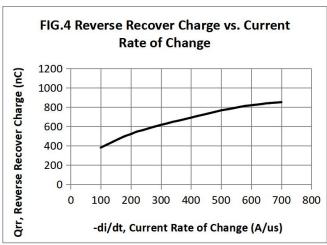
Rev.A01 2 / 4

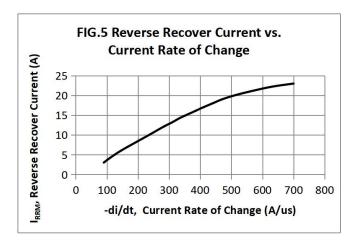


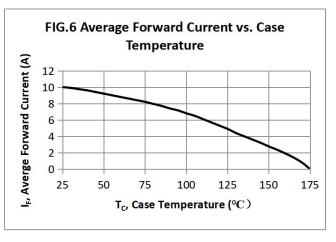


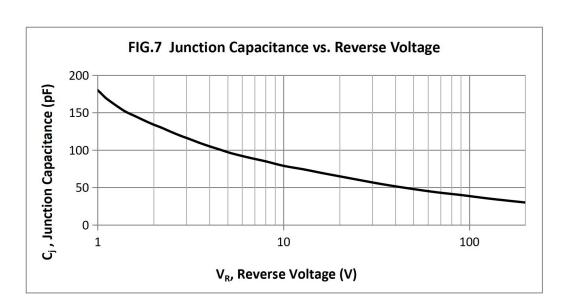












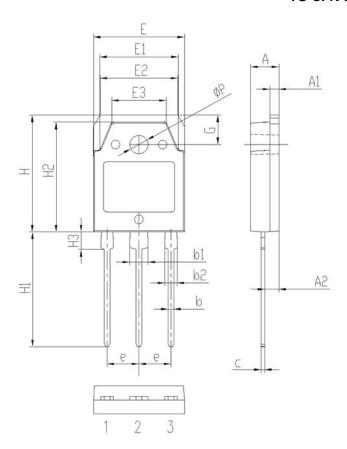
3/4 Rev.A01





Package Information

TO-3PN PACKAGE



Cumphal	Dimensions	(millimeters)
Symbol	Min.	Max.
Α	4.60	5.00
A1	1.30	1.70
A2	2.20	2.60
b	0.80	1.20
b1	2.90	3.30
b2	1.90	2.30
С	0.40	0.80
е	5.25	5.65
E	15.3	15.7
E1	13.2	13.6
E2	13.1	13.5
E3	9.10	9.50
Н	19.7	20.1
H1	19.1	20.1
H2	18.3	18.7
НЗ	2.80	3.20
G	4.80	5.20
ΦР	3.00	3.40

Notice

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Rev.A01 4 / 4